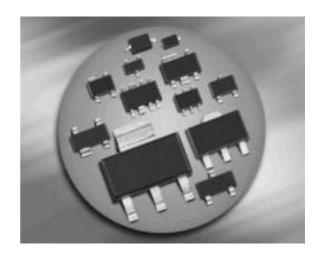


Silicon Switching Diode

- For high-speed switching applications
- Pb-free (RoHS compliant) package¹⁾
- Qualified according AEC Q101







BAL74

BAR74





Туре	Package	Configuration	Marking		
BAL74	SOT23	single	JCs		
BAR74	SOT23	single	JBs		

Maximum Ratings at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	V_{R}	50	V
Peak reverse voltage	V_{RM}	50	
Forward current	I _F	250	mA
Peak forward current	I _{FM}	-	
Surge forward current, $t = 1 \mu s$	I _{FS}	4.5	Α
Non-repetitive peak surge forward current	I _{FSM}	-	
Total power dissipation	P _{tot}	370	mW
<i>T</i> _S ≤ 54°C			
Junction temperature	T _j	150	°C
Storage temperature	T _{stg}	-65 150	

Thermal Resistance

Parameter	Symbol	Value	Unit
Junction - soldering point ²⁾ , BAL74, BAR74	R _{thJS}	≤ 260	K/W

¹Pb-containing package may be available upon special request

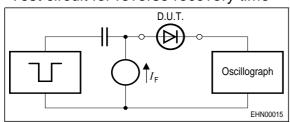
 $^{^{2}\}mbox{For calculation of }R_{\mbox{\scriptsize thJA}}$ please refer to Application Note Thermal Resistance



Electrical Characteristics at $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics			T		
Breakdown voltage	V _(BR)	50	-	-	V
$I_{(BR)} = 100 \mu A$					
Reverse current	I _R				μA
$V_{R} = 50 \text{ V}$		-	-	0.1	
$V_{R} = 50 \text{ V}, T_{A} = 150 ^{\circ}\text{C}$		-	-	100	
Forward voltage	V _F	-	-	1	V
$I_{\rm F} = 100 \text{mA}$					
AC Characteristics					
Diode capacitance	C _T	-	-	2	pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$					
Reverse recovery time	<i>t</i> _{rr}	-	-	4	ns
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 10 mA, measured at $I_{\rm R}$ = 1mA,					
$R_{L} = 100 \ \Omega$					

Test circuit for reverse recovery time



Pulse generator: $t_p = 100$ ns, D = 0.05, $t_r = 0.6$ ns, $R_i = 50\Omega$

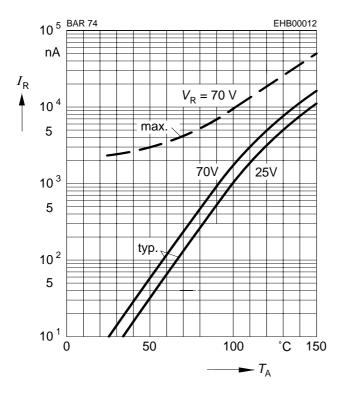
Oscillograph: R = 50Ω , $t_{\rm r}$ = 0.35ns, C \leq 1pF

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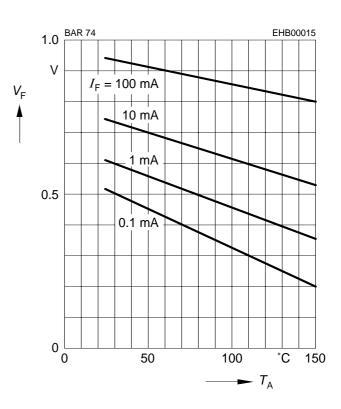
Reverse current $I_R = f(T_A)$

 V_{R} = Parameter

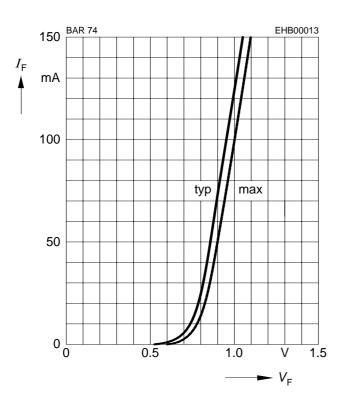


Forward Voltage $V_F = f(T_A)$

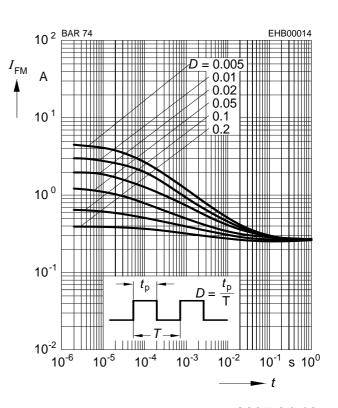
 $I_{\mathsf{F}} = \mathsf{Parameter}$



Forward current $I_F = f(V_F)$



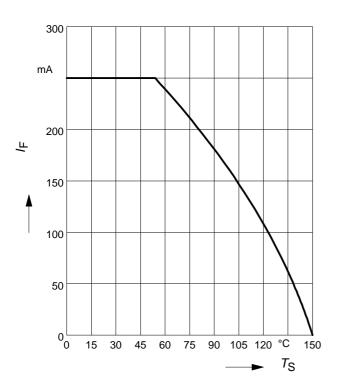
Peak forward current $I_{FM} = f(t_D)$





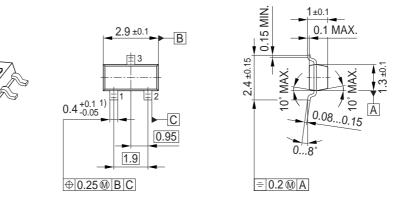
Forward current $I_F = f(T_S)$

BAL74, BAR74



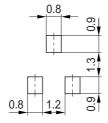


Package Outline

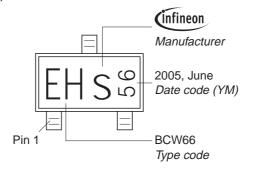


Foot Print



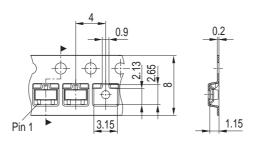


Marking Layout (Example)



Standard Packing

Reel ø180 mm = 3.000 Pieces/Reel Reel ø330 mm = 10.000 Pieces/Reel



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